Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal Overall Length: Between 4.625 inches and 5.625 inches Overall Diameter: 1.047 inches Mounting Facility Quantity: 1
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1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-30
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Threaded stud
Thread Size:
0.500 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
1000.0 reverse voltage, peak
Current Rating Per Characteristic:
150.00 amperes forward current, average
Power Rating Per Characteristic:
180.0 watts small-signal input power, common-collector absolute
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 1 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0